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Highbright 0603 ChipLED



DESCRIPTION

The new ChipLED series have been designed in the smallest SMD package. This innovative ChipLED technology opens the way to

- smaller products of higher performance
- · more design in flexibility
- · enhanced applications

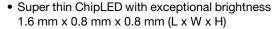
The 0603 LED is an obvious solution for small-scale, high brightness products that are expected to work reliably in an arduous environment.

PRODUCT GROUP AND PACKAGE DATA

• Product group: LED

Package: SMD 0603 ChipLED
Product series: standard
Angle of half intensity: ± 65°

FEATURES





- · High reliability PCB based
- Wavelength (465 to 475) nm (blue), typ. 525 nm (true green), typ. 571 nm (yellow green), (584.5 to 597) nm (yellow), typ. 605 nm (soft orange), typ. 631 nm (super red)
- ROHS
 COMPLIANT
 HALOGEN
 FREE
 GREEN
 (5-2008)
- InGaN blue available with protection diode, device type VLMB1310 with HBM 8000 V
- AllnGaP and InGaN technology
- Viewing angle: Extremely wide 130°
- Grouping parameter: Luminous intensity, wavelength, V_F
- Available in 8 mm tape on 7" diameter reel
- Compatible to IR reflow soldering
- Preconditioning according to JEDEC level 3
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

APPLICATIONS

- · Backlight keypads
- Navigation systems
- Cellular phone displays
- Displays for industrial control systems
- · Miniaturized color effects
- Traffic displays

PARTS TABLE																																						
PART	COLOR	_	JMINO TENSI (mcd)	TY	at I _F	WAVELENGTH (nm)				(nm)				(nm)		(nm)																			ORWAR OLTAC (V)		at I _F	TECHNOLOGY
		MIN.	TYP.	MAX.		MIN.	TYP.	MAX.		MIN.	TYP.	MAX.	-																									
VLMS1300-GS08	Super red	18	54	-	20	-	631	-	20	-	2.0	2.4	20	AllnGaP																								
VLMO1300-GS08	Soft orange	45	90	-	20	-	605	-	20	-	2.0	2.4	20	AllnGaP																								
VLMY1300-GS08	Yellow	28	-	180	20	584.5	-	597	20	1.8	-	2.4	20	AllnGaP																								
VLMY1301-GS08	Yellow	71	-	180	20	584.5	-	597	20	1.8	-	2.4	20	AllnGaP																								
VLMG1300-GS08	Yellow green	18	35	-	20	-	571	-	20	-	2.0	2.4	20	AllnGaP																								
VLMTG1300-GS08	True green	71	-	450	20	-	525	-	20	2.8	3.2	3.6	20	InGaN																								
VLMB1300-GS08	Blue	28	-	180	20	465	-	475	20	2.8	-	3.8	20	InGaN																								
VLMB1310-GS08	Blue	28	-	180	20	465	-	475	20	2.8	-	3.8	20	InGaN																								



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	ATINGS (T_{amb} = 25 °C, unless oth VLMY1300, VLMY1301, VLM			
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
Reverse voltage (1)		V _R	5	V
DC forward current		I _F	30	mA
Surge forward current	1/10 duty cycle, 0.1 ms pulse width	I _{FSM}	80	mA
Power dissipation	T _{amb} ≤ 25 °C	P _V	75	mW
Operating temperature range		T _{amb}	- 35 to + 85	°C
Storage temperature range		T _{stg}	- 45 to + 85	°C
IRED solder conditions	According Vishay specifications	T _{st}	260	°C

Note

⁽¹⁾ Driving the LED in reverse direction is suitable for short term application

	TINGS (T _{amb} = 25 °C, unless oth VLMB1310 (InGaN technology)		d)	
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
DC forward current		I _F	20	mA
Surge forward current	1/10 duty cycle, 0.1 ms pulse width	I _{FSM}	100	mA
Power dissipation	T _{amb} ≤ 25 °C	P _V	76	mW
ESD thershold, for VLMB1310 with protection only	НВМ	th _{ESD HBM}	8000	V
Operating temperature range		T _{amb}	- 20 to + 80	°C
Storage temperature range		T _{stg}	- 30 to + 100	°C
IRED solder conditions	According Vishay specifications	T _{st}	260	°C

OPTICAL AND ELECTRICATION OF THE PROPERTY OF T	AL CHARACTERISTICS (T _{an}	_{nb} = 25 °C, u	nless othe	erwise spe	cified)	
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Luminous intensity	I _F = 20 mA	I _V	18	54	-	mcd
Dominant wavelength	I _F = 20 mA	λ_{d}	=	631	-	nm
Peak wavelength	I _F = 20 mA	λ_{p}	-	639	-	nm
Angle of half intensity	I _F = 20 mA	φ	=	± 65	-	deg
Spectral line half width	I _F = 20 mA	Δλ	-	20	-	nm
Forward voltage	I _F = 20 mA	V _F	-	2.0	2.4	V
Junction capacitance	V _R = 0 V, f = 1 MHz	C _j	-	40	-	pF
Reverse current	V _R = 5 V	I _R	=	-	10	μA

OPTICAL AND ELECTRIC VLMO1300, SOFT ORAN	CAL CHARACTERISTICS (T _{an} Ge	_{nb} = 25 °C, ur	nless othe	erwise spe	ecified)	
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Luminous intensity	I _F = 20 mA	I _V	45	90	-	mcd
Dominant wavelength	I _F = 20 mA	λ_{d}	-	605	-	nm
Peak wavelength	I _F = 20 mA	λρ	-	611	-	nm
Angle of half intensity	I _F = 20 mA	φ	-	± 65	-	deg
Spectral line half width	I _F = 20 mA	Δλ	-	17	-	nm
Forward voltage	$I_F = 20 \text{ mA}$	V _F	-	2.0	2.4	V
Junction capacitance	V _R = 0 V, f = 1 MHz	C _j	-	40	-	pF
Reverse current	V _R = 5 V	I _R	-	-	10	μΑ

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OPTICAL AND ELECTF VLMY1300, VLMY1301		STICS (T _{amb} =	25 °C, unl	ess other	wise spec	cified)	
PARAMETER	TEST CONDITION	PART NUMBER	SYMBOL	MIN.	TYP.	MAX.	UNIT
Luminous intensity	I _E = 20 mA	VLMY1300	I _V	28	-	180	mcd
Luminous intensity	IF = 20 IIIA	VLMY1301	I _V	71	-	180	mcd
Dominant wavelength	I _F = 20 mA		λ_{d}	584.5	=	597	nm
Peak wavelength	I _F = 20 mA		λ_{p}	-	588	-	nm
Angle of half intensity	$I_F = 20 \text{ mA}$		φ	-	± 65		deg
Spectral line half width	I _F = 20 mA		Δλ	-	15	-	nm
Forward voltage	$I_F = 20 \text{ mA}$		V _F	1.8	-	2.4	V
Junction capacitance	V _R = 0 V, f = 1 MHz		C _j	-	40	-	pF
Reverse current	V _R = 5 V		I _R	-	-	10	μA

OPTICAL AND ELECTRIC VLMG1300, YELLOW GR	EAL CHARACTERISTICS (T _{amb}	= 25 °C, unl	ess other	wise spec	cified)	
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Luminous intensity	I _F = 20 mA	I _V	18	35	-	mcd
Dominant wavelength	I _F = 20 mA	λ_{d}	-	571	-	nm
Peak wavelength	I _F = 20 mA	λ_{p}	-	574	-	nm
Angle of half intensity	I _F = 20 mA	φ	-	± 65	-	deg
Spectral line half width	I _F = 20 mA	Δλ	-	15	-	nm
Forward voltage	I _F = 20 mA	V _F	-	2.0	2.4	V
Junction capacitance	V _R = 0 V, f = 1 MHz	C _j	-	40	-	pF
Reverse current	V _R = 5 V	I _R	-	-	10	μA

OPTICAL AND ELECTRICATION VLMTG1300, TRUE GREE	AL CHARACTERISTICS (T _{amb} in	s = 25 °C, unle	ess other	wise spec	cified)	
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Luminous intensity	I _F = 20 mA	I _V	71	-	450	mcd
Dominant wavelength	I _F = 20 mA	λ_{d}	-	525	-	nm
Peak wavelength	I _F = 20 mA	λ_{p}	-	530	-	nm
Angle of half intensity	I _F = 20 mA	φ	-	± 65	-	deg
Spectral line half width	I _F = 20 mA	Δλ	-	35	-	nm
Forward voltage	I _F = 20 mA	V_{F}	2.8	3.2	3.6	V
Reverse current	V _R = 5 V	I _R	-	-	10	μΑ

OPTICAL AND ELECTRICAL (VLMB1300, VLMB1310, BLU	· · · · · · · · · · · · · · · · · · ·	_{nb} = 25 °C, unle	ess other	wise spec	cified)	
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Luminous intensity	I _F = 20 mA	Ι _V	28	-	180	mcd
Dominant wavelength	I _F = 20 mA	λ_{d}	465	-	475	nm
Peak wavelength	I _F = 20 mA	λρ	-	468	-	nm
Angle of half intensity	I _F = 20 mA	φ	-	± 65	-	deg
Spectral line half width	I _F = 20 mA	Δλ	-	25	-	nm
Forward voltage	I _F = 20 mA	V _F	2.8	-	3.8	V
Reverse current (except VLMB1310)	V _R = 5 V	I _R	-	-	10	μΑ
Reverse voltage (VLMB1310 only)	I _R = 10 mA	V_{R}	0.6	-	1.2	V



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LUMINOUS INTENSITY CLASSIFICATION					
GROUP	LUMINOUS IN	TENSITY (mcd)			
GROUP	MIN.	MAX.			
М	18	28			
N	28	45			
Р	45	71			
Q	71	112			
R	112	180			
S	180	280			
Т	280	450			

Note

 Luminous intensity is tested at a current pulse duration of 25 ms and an accuracy of ± 15 %.

The above type numbers represent the order groups which include only a few brightness groups. Only one group will be shipped on each reel (there will be no mixing of two groups on each reel). In order to ensure availability, single brightness groups will not be orderable.

In a similar manner for colors where wavelength groups are measured and binned, single wavelength groups will be shipped in any one reel.

In order to ensure availability, single wavelength groups will not be orderable

COLOR CLASSIFICATION					
COLOR	GROUP	DOMINANT WAVELENGTH (nm)			
		MIN.	MAX.		
	Н	584.5	587.5		
	J	587.5	589.5		
Yellow	K	589.5	592		
	L	592	594.5		
	М	594.5	597		
	С	567.5	570.5		
Yellow green	D	570.5	573.5		
	E	573.5	576.5		
	AP	520	525		
True green	AQ	525	530		
	AR	530	535		
Blue	AC	465	470		
Dide	AD	470	475		

Note

 Wavelengths are tested at a current pulse duration of 25 ms and an accuracy of ± 1 nm

001.00	GROUP	FORWARD VOLTAGE (V)		
COLOR	GNOOF	MIN.	MAX.	
Yellow	F2	1.8	2.1	
reliow	F3	2.1	2.4	
	4	1.9	2	
	5	2	2.1	
Yellow green	6	2.1	2.2	
	7	2.2	2.3	
	8	2.3	2.4	
	D7	2.8	3	
Twise areas	D8	3	3.2	
True green	D9	3.2	3.4	
	D10	3.4	3.6	
	D7	2.8	3	
	D8	3	3.2	
Blue	D9	3.2	3.4	
	D10	3.4	3.6	
	D11	3.6	3.8	

Note

• Forward voltage is measured with a tolerance of \pm 0.1 V.

TYPICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

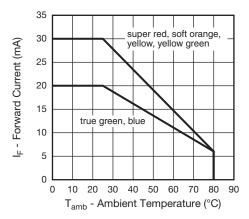


Fig. 1 - Forward Current vs. Ambient Temperature

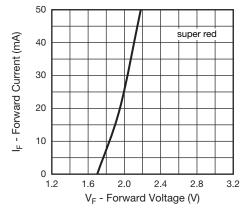


Fig. 2 - Forward Current vs. Forward Voltage (super red)

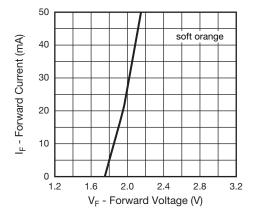


Fig. 3 - Forward Current vs. Forward Voltage (soft orange)

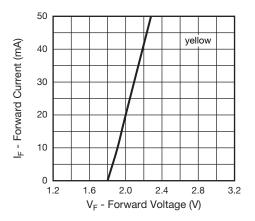


Fig. 4 - Forward Current vs. Forward Voltage (yellow)

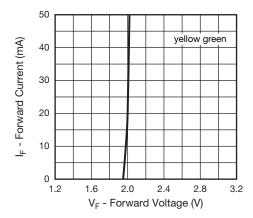


Fig. 5 - Forward Current vs. Forward Voltage (yellow green)

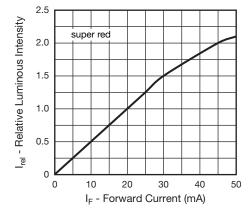


Fig. 6 - Relative Luminous Intensity vs. Forward Current (super red)

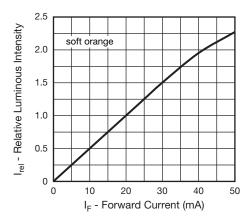


Fig. 7 - Relative Luminous Intensity vs. Forward Current (soft orange)

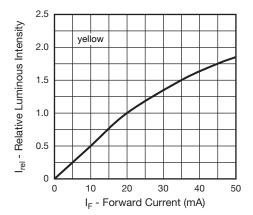


Fig. 8 - Relative Luminous Intensity vs. Forward Current (yellow)

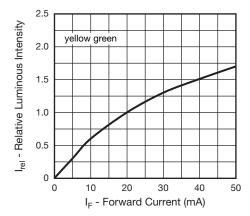


Fig. 9 - Relative Luminous Intensity vs. Forward Current (yellow green)

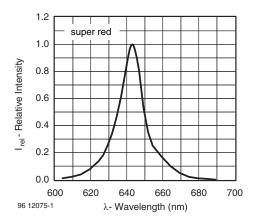


Fig. 10 - Relative Intensity vs. Wavelength (super red)

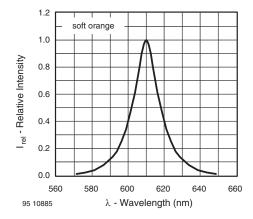


Fig. 11 - Relative Intensity vs. Wavelength (soft orange)

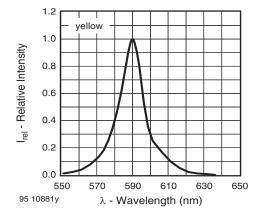


Fig. 12 - Relative Intensity vs. Wavelength (yellow)

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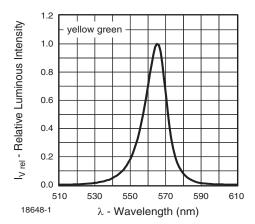


Fig. 13 - Relative Intensity vs. Wavelength (yellow green)

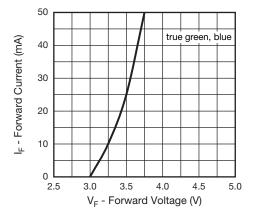


Fig. 14 - Forward Current vs. Forward Voltage (true green, blue)

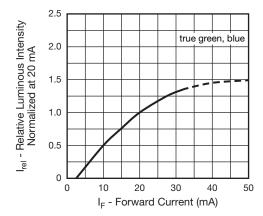
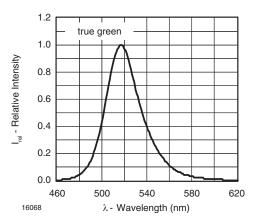


Fig. 15 - Relative Luminous Intensity vs. Forward Current (true green, blue)



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Fig. 16 - Relative Intensity vs. Wavelength (true green)

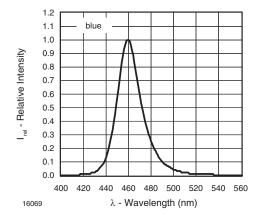


Fig. 17 - Relative Intensity vs. Wavelength (blue)

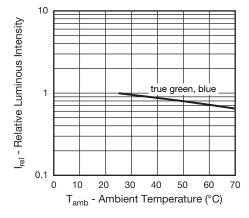


Fig. 18 - Relative Luminous Intensity vs. Ambient Temperature

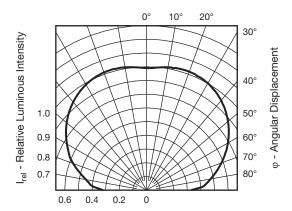
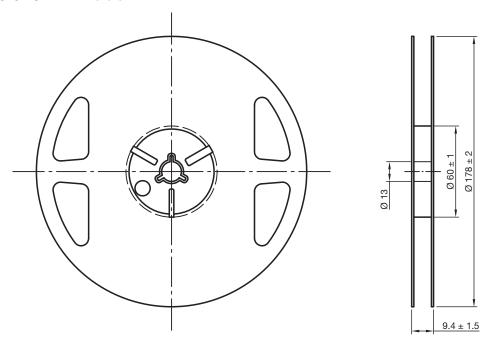


Fig. 19 - Relative Luminous Intensity vs. Angular Displacement

REEL DIMENSIONS in millimeters



Drawing-No.: 9.800-5122.01-4

Issue: 2; 03.11.11

22611

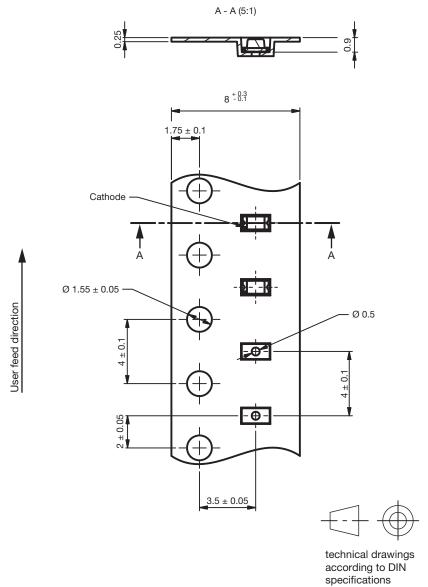
Ø 178 ± 2

technical drawings according to DIN specifications

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TAPE DIMENSIONS in millimeters

VLMG 13.., VLMY 13.., VLMO 13.., VLMS 13.., VLMB 13.., VLMB131..



Drawing-No.: 9.700-5386.01-4

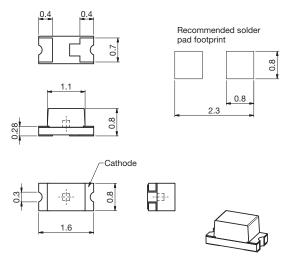
Issue: 1; 17.10.11

22614

PACKAGE DIMENSIONS in millimeters

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VLMG 13.., VLMY 13.., VLMO 13.., VLMS 13..



Not indicated tolerances ± 0.2

Drawing-No.: 6.541-5092.01-4

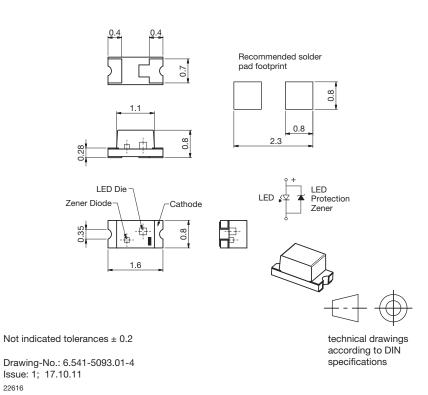
Issue: 1; 17.10.11

22615

22616

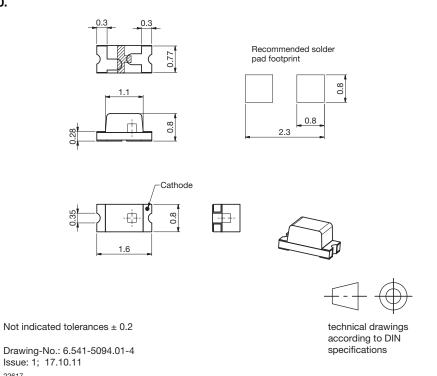
technical drawings according to DIN specifications

VLMB 131..



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VLMB 130., VLMTG 130.



SOLDERING PROFILE

Preconditioning acc. to JEDEC Level 3 300 max 260 °C -255 °C 245 °C 240 °C 217 °C

IR Reflow Soldering Profile for lead (Pb)-free Soldering

22617

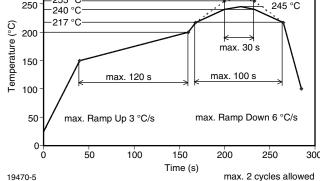
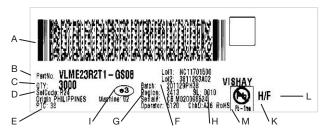


Fig. 20 - Vishay Lead (Pb)-free Reflow Soldering Profile (according to J-STD-020C)

BAR CODE PRODUCT LABEL (example only)



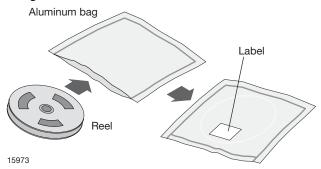
- A. 2D barcode
- B. Vishay part number
- C. Quantity
- D. PTC = selection code (binning)
- E. Code of manufacturing plant
- F. Batch = date code: year / week / plant code
- G. Region code
- H. SL = sales location
- I. Terminations finishing
- K. Lead (Pb)-free symbol
- L. Halogen-free symbol
- M.RoHS symbol



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DRY PACKING

The reel is packed in an anti-humidity bag to protect the devices from absorbing moisture during transportation and storage.



FINAL PACKING

The sealed reel is packed into a cardboard box. A secondary cardboard box is used for shipping purposes.

RECOMMENDED METHOD OF STORAGE

Dry box storage is recommended as soon as the aluminum bag has been opened to prevent moisture absorption. The following conditions should be observed, if dry boxes are not available:

- Storage temperature 10 °C to 30 °C
- Storage humidity ≤ 60 % RH max.

After more than 168 h under these conditions moisture content will be too high for reflow soldering.

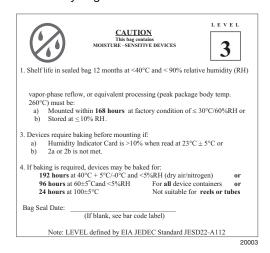
In case of moisture absorption, the devices will recover to the former condition by drying under the following condition:

192 h at 40 °C + 5 °C / - 0 °C and < 5 % RH (dry air / nitrogen) or

96 h at 60 °C + 5 °C and < 5 % RH for all device containers or

24 h at 100 °C + 5 °C not suitable for reel or tubes.

An EIA JEDEC standard JESD22-A112 level 3 label is included on all dry bags.



Example of JESD22-A112 Level 3 Label

ESD PRECAUTION

Proper storage and handling procedures should be followed to prevent ESD damage to the devices especially when they are removed from the antistatic shielding bag. Electro-static sensitive devices warning labels are on the packaging.

VISHAY SEMICONDUCTORS STANDARD BAR CODE LABELS

The Vishay Semiconductors standard bar code labels are printed at final packing areas. The labels are on each packing unit and contain Vishay Semiconductors specific data.



Legal Disclaimer Notice

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